FAIRCHILD

SEMICONDUCTOR

RHRA1560CC Hyperfast Rectifier

Features

- High Speed Switching ($t_{rr} < 35 ns$)
- High Reverse Voltage and High Reliability
- Avalanche Energy Rated
- High Operating Temperature

Applications

- General Purpose
- Switching Mode Power Supply
- Free-wheeling diode for motor application
- Power switching circuits

June 2007



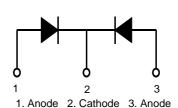
15A, 600V Hyperfast Rectifier

The RHRA1560CC is a hyperfast rectifier (t_{rr} <35ns) with soft recovery characteristics. It has half the recovery time of ultrafast diodes and is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as freewheeling/clamping diodes and rectifier in a variety of switching power supplies and other power swithching applications. Its low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits reducing power loss in the switching transistors.







1. Anode 2. Cathode 3. Anode

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{RRM}	Peak Repetitive Reverse Voltage	600	V	
V _{RWM}	Working Peak Reverse Voltage	600	V	
V _R	DC Blocking Voltage	600	V	
I _{F(AV)}	Average Rectified Forward Current @ T _C = 140 °C	15	A	
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	200	A	
T _{J,} T _{STG}	Operating Junction and Storage Temperature	- 65 to +175	°C	

Thermal Characteristics T_C = 25°C unless otherwise noted

Symbol	Parameter	Мах	Units
$R_{ ext{ heta}JC}$	Maximum Thermal Resistance, Junction to Case	1.5	°C/W

Package Marking and Ordering Information

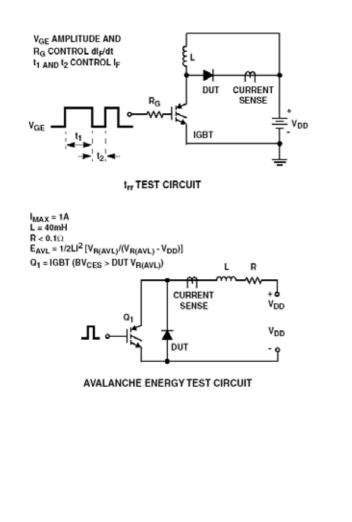
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
RHRA1560CC	RHRA1560CCTU	TO-3PN	-	-	30

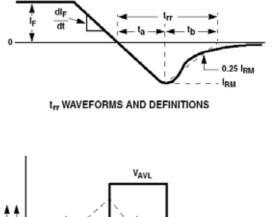
Parameter V _{FM} ¹	Conditions		Min.	Тур.	Max	2.1 V
	I _F = 15A I _F = 15A	T _C = 25 °C T _C = 150 °C	-	-	2.1 1.7	
I _{RM} ¹	$V_{R} = 600V$ $V_{R} = 600V$	T _C = 25 °C T _C = 150 °C	-	-	100 500	μΑ μΑ
t _{rr}	$I_F = 1A$, di/dt = 100A/µs, $V_{CC} = 30V$ $I_F = 15A$, di/dt = 100A/µs, $V_{CC} = 390V$	T _C = 25 °C T _C = 25 °C	-	-	35 40	ns ns
t _a t _b Q _{rr}	I _F =15A, di/dt = 100A/μs, V _{CC} = 390V	$T_{C} = 25 \text{ °C}$	- - -	20 15 40	- - -	ns ns nC
CJ	V _R = 10V, I _F =0A		-	60	-	pF
W _{AVL}	Avalanche Energy (L = 40mH)		20	-	-	mJ

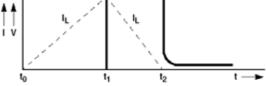
Notes:

1. Pulse : Test Pulse width = $300\mu s$, Duty Cycle = 2%

Test Circuit and Waveforms



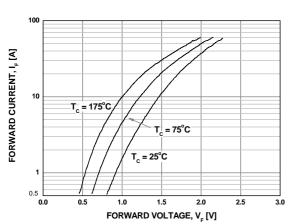




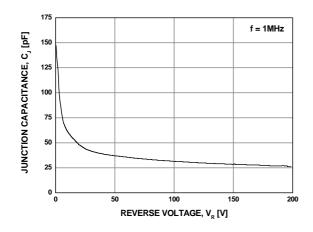
AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

Typical Performance Characteristics T_C = 25°C unless otherwise noted











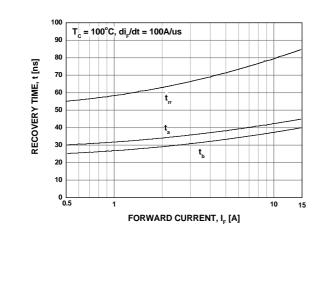


Figure 2. Typical Reverse Current

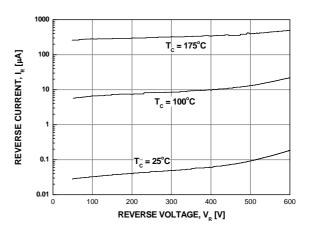
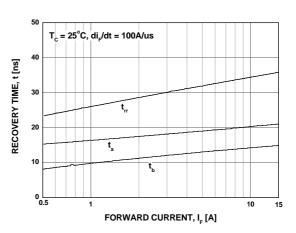
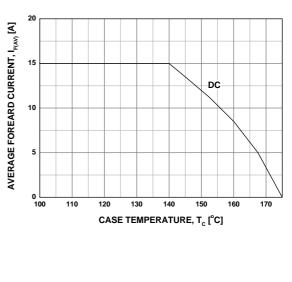
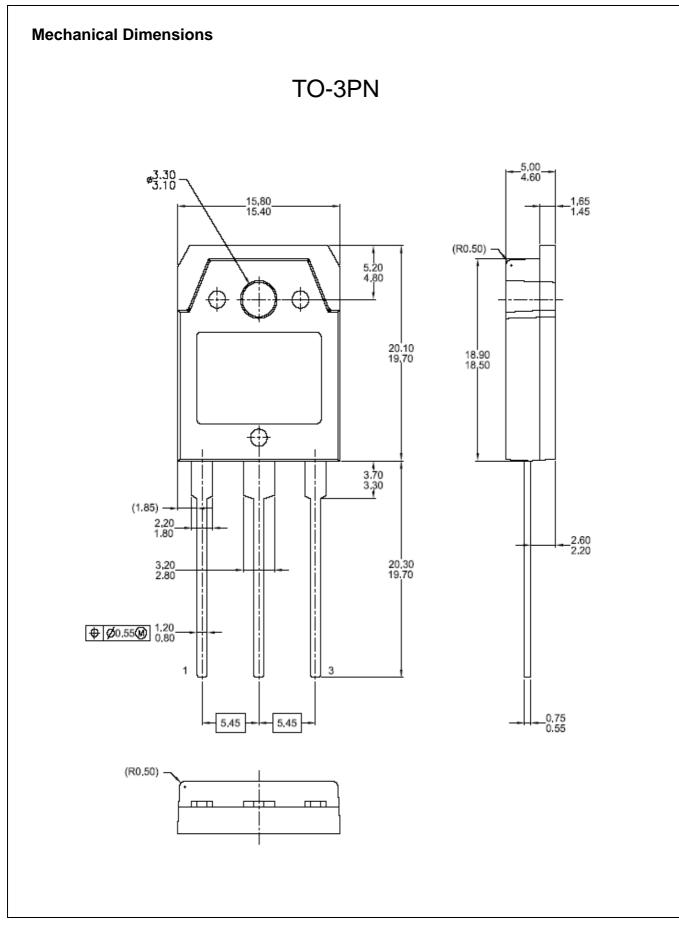


Figure 4. Recovery Time vs. Forward Current











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